

MOSFETs Silicon P-Channel MOS (U-MOSVI)

# TPH1R712MD

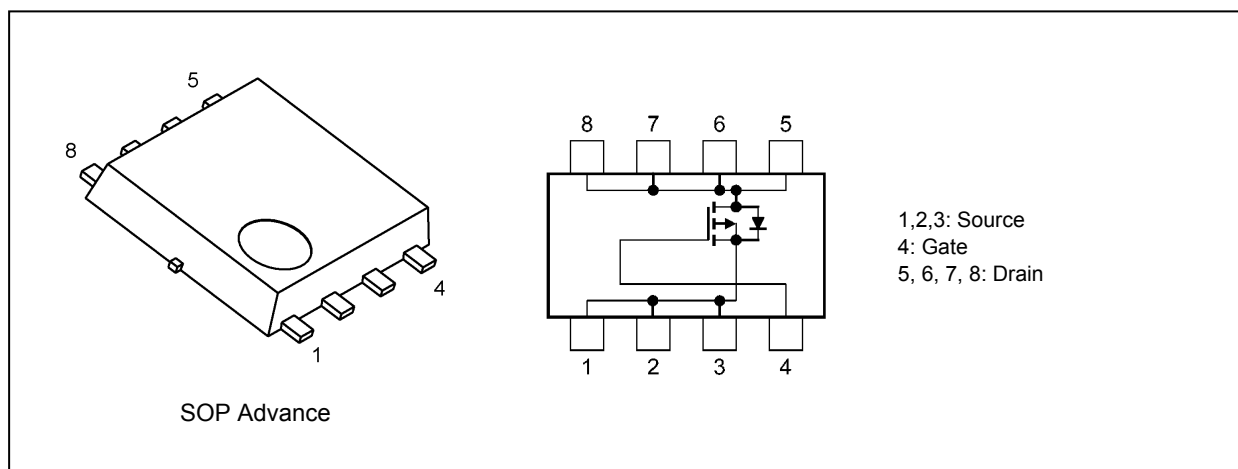
## 1. Applications

- Lithium-Ion Secondary Batteries
- Power Management Switches

## 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 1.35 \text{ m}\Omega$  (typ.) ( $V_{GS} = -4.5 \text{ V}$ )
- (2) Low leakage current:  $I_{DSS} = -10 \text{ }\mu\text{A}$  (max) ( $V_{DS} = -20 \text{ V}$ )
- (3) Enhancement mode:  $V_{th} = -0.5 \text{ to } -1.2 \text{ V}$  ( $V_{DS} = -10 \text{ V}$ ,  $I_D = -1.0 \text{ mA}$ )

## 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) ( $T_a = 25 \text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	-20	V
Gate-source voltage	$V_{GSS}$	$\pm 12$	
Drain current (DC)	$I_D$	-60	A
Drain current (pulsed)	$I_{DP}$	-200	
Power dissipation	$P_D$	78	W
Power dissipation	$P_D$	2.8	
Power dissipation	$P_D$	1.6	
Single-pulse avalanche energy	$E_{AS}$	468	mJ
Single-pulse avalanche current	$I_{AS}$	-60	A
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

2014-03

## 5. Thermal Characteristics

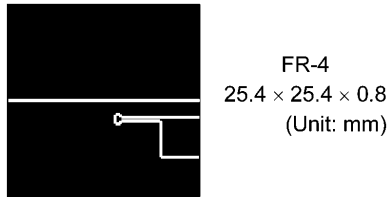
Characteristics			Symbol	Max	Unit
Channel-to-case thermal resistance	$(T_c = 25\text{ }^\circ\text{C})$		$R_{th(ch-c)}$	1.60	$^\circ\text{C/W}$
Channel-to-ambient thermal resistance	$(t = 10\text{ s})$	(Note 2)	$R_{th(ch-a)}$	44.6	
Channel-to-ambient thermal resistance	$(t = 10\text{ s})$	(Note 3)	$R_{th(ch-a)}$	78.1	

Note 1: Ensure that the channel temperature does not exceed 150 °C.

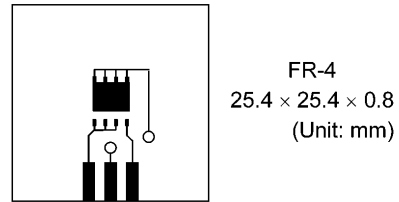
Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4:  $V_{DD} = -16\text{ V}$ ,  $T_{ch} = 25\text{ }^\circ\text{C}$  (initial),  $L = 100\text{ }\mu\text{H}$ ,  $I_{AS} = -60\text{ A}$



**Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)**



**Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)**

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

### 6. Electrical Characteristics

#### 6.1. Static Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 12\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 0.1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}$	—	—	-10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$	-20	—	—	V
Drain-source breakdown voltage (Note 5)	$V_{(BR)DSX}$	$I_D = -10\text{ mA}, V_{GS} = 8.0\text{ V}$	-12	—	—	
Gate threshold voltage	$V_{th}$	$V_{DS} = -10\text{ V}, I_D = -1.0\text{ mA}$	-0.5	—	-1.2	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = -2.5\text{ V}, I_D = -30\text{ A}$	—	2.0	2.7	$\text{m}\Omega$
		$V_{GS} = -4.5\text{ V}, I_D = -30\text{ A}$	—	1.35	1.7	

Note 5: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

#### 6.2. Dynamic Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	10900	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	1550	—	
Output capacitance	$C_{oss}$		—	2010	—	
Switching time (rise time)	$t_r$	See Fig. 6.2.1.	—	14	—	ns
Switching time (turn-on time)	$t_{on}$		—	27	—	
Switching time (fall time)	$t_f$		—	512	—	
Switching time (turn-off time)	$t_{off}$		—	1620	—	

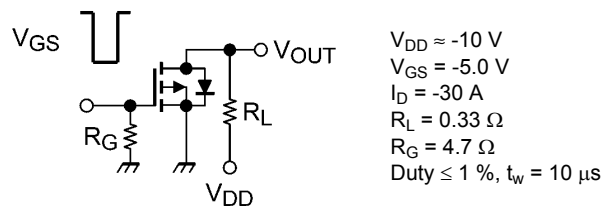


Fig. 6.2.1 Switching Time Test Circuit

#### 6.3. Gate Charge Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx -16\text{ V}, V_{GS} = -5.0\text{ V}, I_D = -60\text{ A}$	—	182	—	nC
Gate-source charge 1	$Q_{gs1}$		—	23	—	
Gate-drain charge	$Q_{gd}$		—	56	—	

#### 6.4. Source-Drain Characteristics ( $T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note6)	$I_{DRP}$	—	—	—	-200	A
Diode forward voltage	$V_{DSF}$	$I_{DR} = -60\text{ A}, V_{GS} = 0\text{ V}$	—	—	1.2	V

Note6: Ensure that the channel temperature does not exceed  $150\text{ }^\circ\text{C}$ .

## 7. Marking

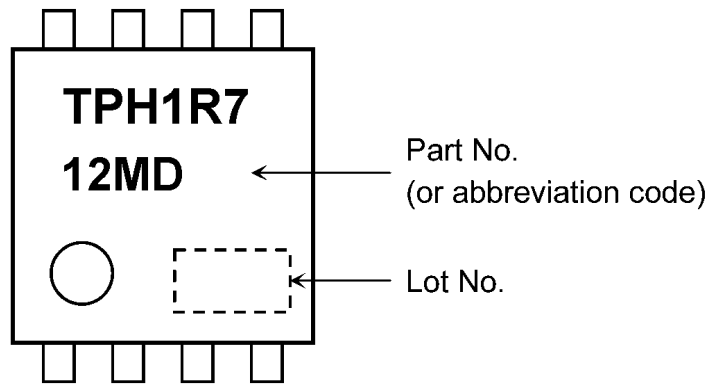
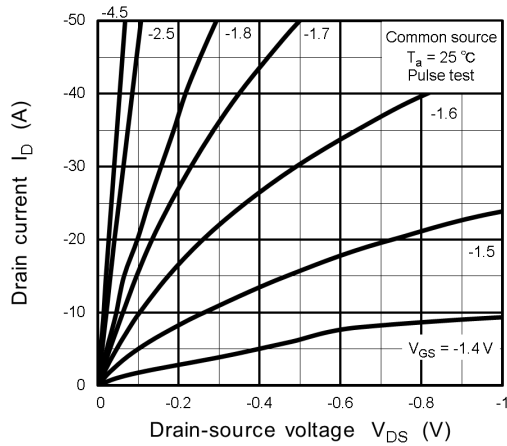
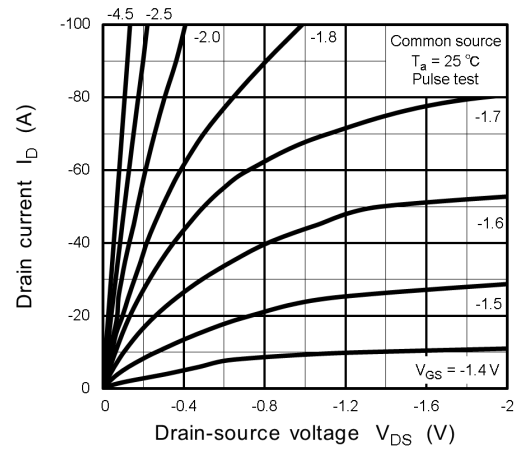


Fig. 7.1 Marking

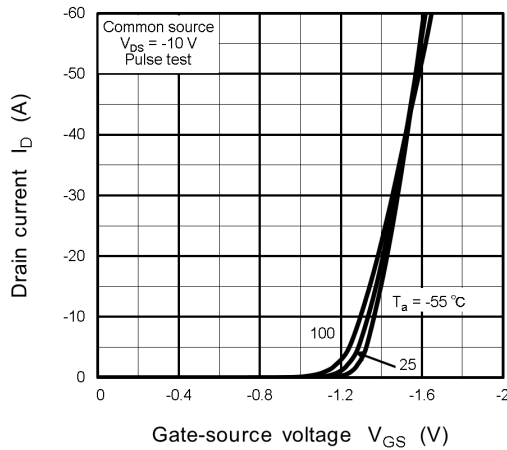
### 8. Characteristics Curves (Note)



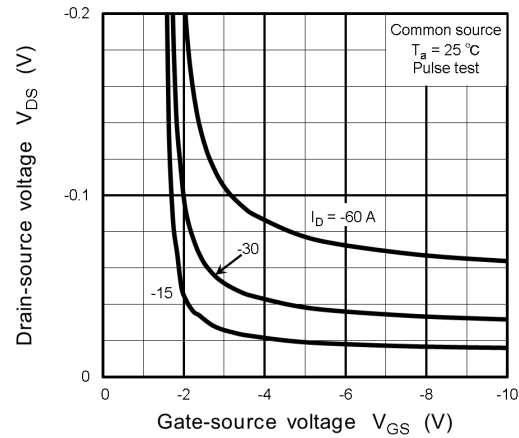
**Fig. 8.1  $I_D - V_{DS}$**



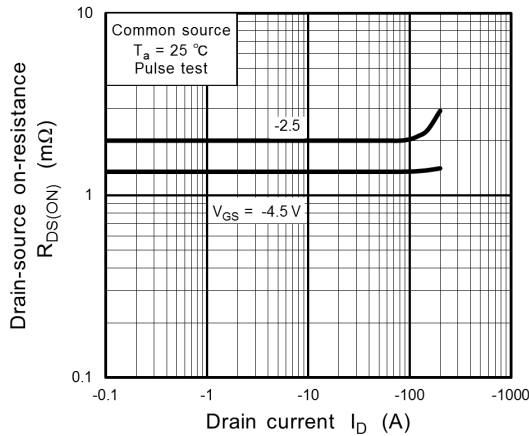
**Fig. 8.2  $I_D - V_{DS}$**



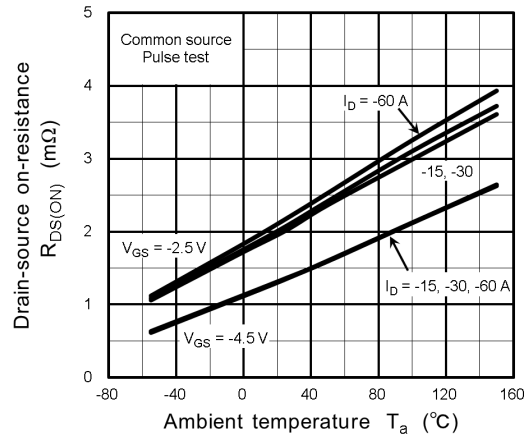
**Fig. 8.3  $I_D - V_{GS}$**



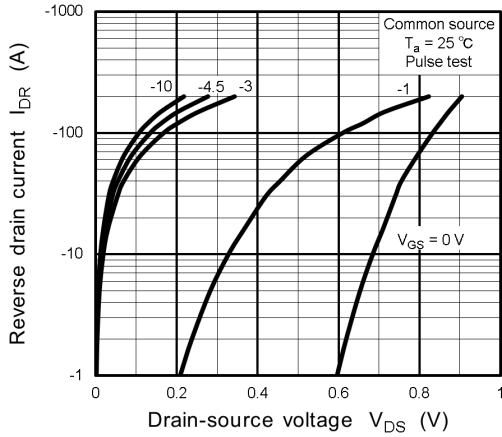
**Fig. 8.4  $V_{DS} - V_{GS}$**



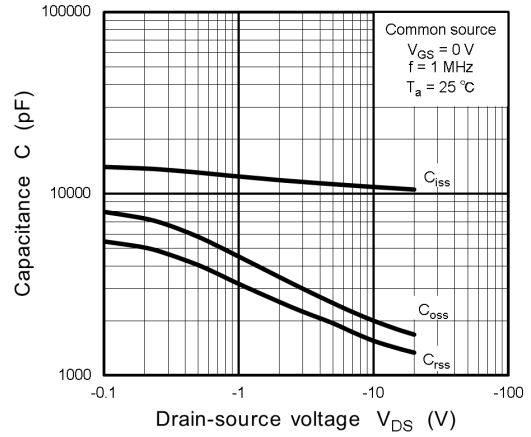
**Fig. 8.5  $R_{DS(ON)} - I_D$**



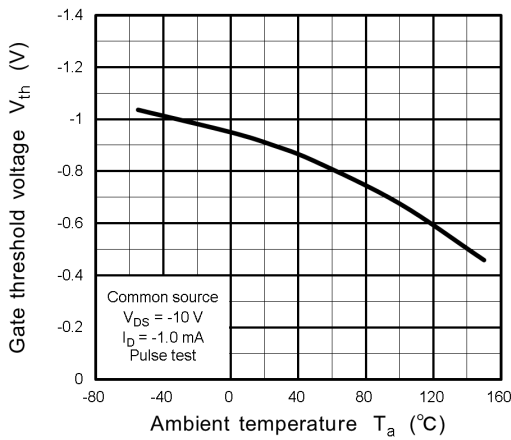
**Fig. 8.6  $R_{DS(ON)} - T_a$**



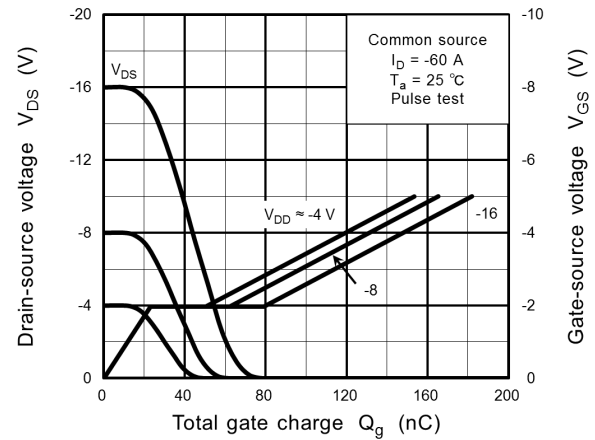
**Fig. 8.7  $I_{DR} - V_{DS}$**



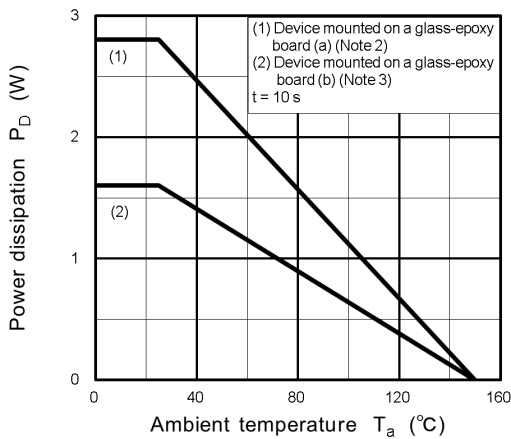
**Fig. 8.8 Capacitance -  $V_{DS}$**



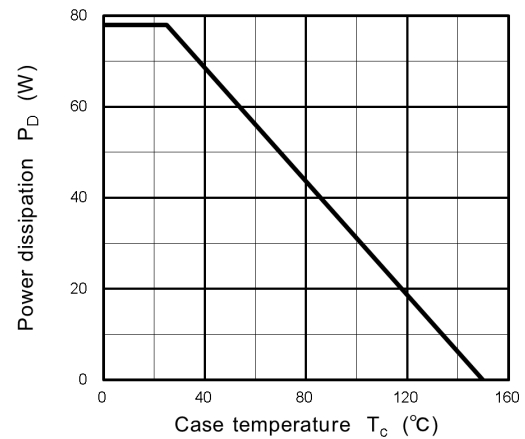
**Fig. 8.9  $V_{th} - T_a$**



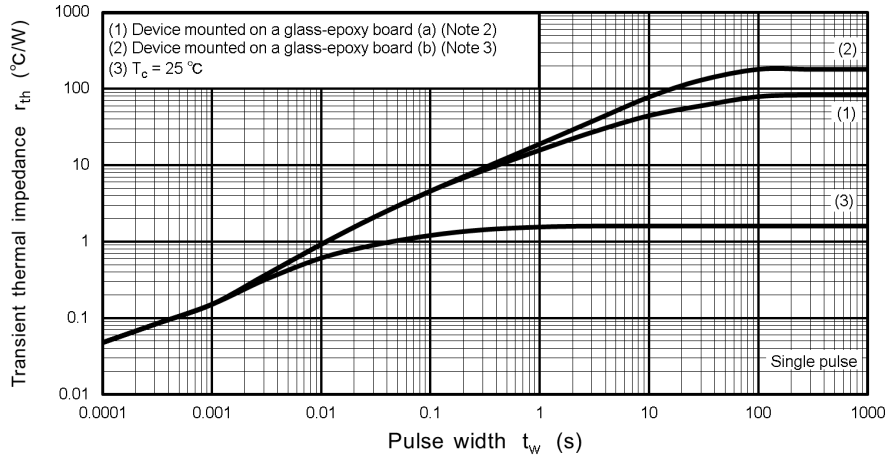
**Fig. 8.10 Dynamic Input/Output Characteristics**



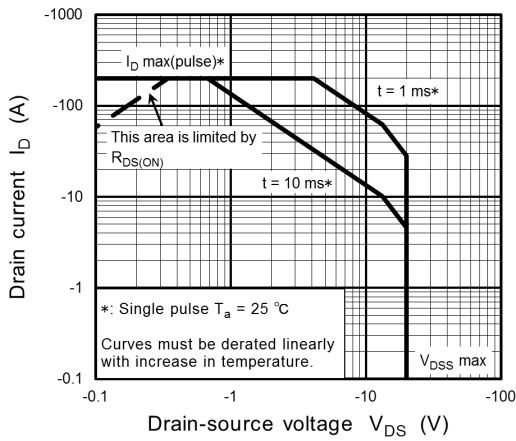
**Fig. 8.11  $P_D - T_a$   
(Guaranteed Maximum)**



**Fig. 8.12  $P_D - T_c$   
(Guaranteed Maximum)**



**Fig. 8.13  $r_{th} - t_w$**   
**(Guaranteed Maximum)**



**Fig. 8.14 Safe Operating Area**  
**(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.





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